DATASHEET

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER AC INPUT PHOTOCOUPLER H11AAX Series



Features

- H11AAX series: H11AA1, H11AA2, H11AA3, H11AA4
- High isolation voltage between input and output
- Viso = 5000 Vrms
- Creepage distance >7.62 mm
- Compact dual-in-line package
- · The product itself will remain within RoHS compliant version
- Compliance with EU REACH
- UL and cUL approved(No. E214129)
- VDE approved (No.132249)
- SEMKO approved
- NEMKO approved
- · DEMKO approved
- FIMKO approved
- CQC approved

Description

The H11AAX series of devices each consist of two infrared emitting diode, connected in inverse parallel, optically coupled to a phototransistor detector.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- · AC line monitor
- Unknown polarity DC sensor
- Telephone line interface

3

Schematic

Pin Configuration

1. Anode / Cathode

- 2. Cathode / Anode 3. No Connection
- 4. Emitter
- 5. Collector
- 6. Base



Absolute Maximum Ratings (Ta=25℃)

	Symbol	Rating	Unit
Forward current	IF	60	mA
Peak forward current (t = 10µs)	I _{FM}	1	А
Power dissipation (TA = 25°C)	5	120	mW
Derating factor (above 90°C)	P _D —	3.8	mW/°C
Power dissipation ($T_A = 25^{\circ}C$) No derating up to 100°C	Pc	150	mW
Collector-Emitter voltage	V _{CEO}	80	V
Collector-Base voltage	V _{CBO}	80	V
Emitter-Collector voltage	V _{ECO}	7	V
Total Power Dissipation		200	mW
Isolation Voltage*1		5000	V rms
Operating Temperature		-55 to 100	°C
Storage Temperature		-55 to 125	°C
Soldering Temperature*2		260	°C
	Peak forward current (t = 10µs)Power dissipation (TA = 25°C) Derating factor (above 90°C)Power dissipation (TA = 25°C) No derating up to 100°CCollector-Emitter voltageCollector-Base voltageEmitter-Collector voltageissipation uge^{*1} operature 	Peak forward current (t = 10µs) I_{FM} Power dissipation (TA = 25°C) Derating factor (above 90°C) P_D Power dissipation (TA = 25°C) No derating up to 100°C P_C Collector-Emitter voltage V_{CEO} Collector-Base voltage V_{CBO} Emitter-Collector voltage V_{ECO} issipation P_{TOT} qe^{*1} V_{ISO} nperature T_{OPR}	Peak forward current (t = 10µs)IFM1Power dissipation (TA = 25°C) Derating factor (above 90°C) P_D 120 P_D 3.8 P_D 3.8 Power dissipation (TA = 25°C) No derating up to 100°C P_C 150Collector-Emitter voltage V_{CEO} 80Collector-Base voltage V_{CBO} 80Emitter-Collector voltage V_{ECO} 7issipation P_{TOT} 200 qge^{*1} V_{ISO} 5000nperature T_{OPR} -55 to 100erature T_{STG} -55 to 125

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25 $^{\circ}$ C unless specified otherwise)

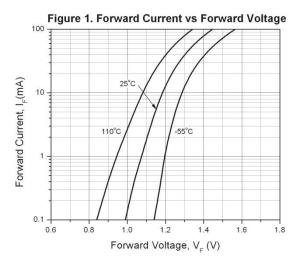
Input							
Pa	arameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Vo	orward Voltage		-	1.2	1.5	V	$I_F = \pm 10 \text{mA}$
Input capac	itance	Cin	-	80	-	pF	V = 0, f = 1MHz
Output							
Pa	arameter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Er	mitter dark current	ICEO	-	-	50	nA	$V_{CE} = 10V, I_F = 0mA$
Collector-Er		BV _{CEO}	80	-	-	V	$I_C = 1mA$
Collector-Babreakdown		ВVсво	80	-	-	V	$I_{\rm C} = 0.1 {\rm mA}$
Emitter-Coll breakdown		BV _{ECO}	7	-	-	V	$I_E = 0.1 mA$
Collector-Er	Collector-Emitter capacitance		-	10	-	pF	VCE = 0V, f = 1MHz
	characteristics	Symbol	Min	Тур.	Max.	Unit	Condition
	H11AA1		20	-	-		
Current	H11AA1 H11AA2		20 10	-	-		
Current Transfer ratio		- CTR			- - -	%	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$
Transfer	H11AA2	CTR	10	-		%	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$
Transfer	H11AA2 H11AA3 H11AA4	- CTR	10 50	-	- - - 2.0	%	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$ $I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$
Transfer ratio	H11AA2 H11AA3 H11AA4 netry mitter	- CTR	10 50 100	-		% V	
Transfer ratio CTR Symn Collector-e	H11AA2 H11AA3 H11AA4 netry mitter voltage	 	10 50 100		2.0		$I_{F} = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$
Transfer ratio CTR Symn Collector-e saturation Isolation re	H11AA2 H11AA3 H11AA4 netry mitter voltage	- V _{CE(sat)}	10 50 100 0.5 -		2.0	V	$I_F = \pm 10 \text{mA}$, $V_{CE} = 10 \text{V}$ $I_F = \pm 10 \text{mA}$, $I_C = 0.5 \text{mA}$ $V_{IO} = 500 \text{Vdc}$,
Transfer ratio CTR Symn Collector-e saturation Isolation re	H11AA2 H11AA3 H11AA4 hetry mitter voltage esistance ut capacitance	V _{CE(sat)}	10 50 100 0.5 - 10 ¹¹	- - - - -	2.0	VΩ	$I_{F} = \pm 10 \text{mA}, V_{CE} = 10 \text{V}$ $I_{F} = \pm 10 \text{mA}, I_{C} = 0.5 \text{mA}$ $V_{IO} = 500 \text{Vdc},$ $40 \sim 60\% \text{ R.H.}$
Transfer ratio CTR Symm Collector-e saturation Isolation re Input-outpu	H11AA2 H11AA3 H11AA4 hetry mitter voltage esistance ut capacitance he	V _{CE(sat)} R _{IO} C _{IO}	10 50 100 0.5 - 10 ¹¹ -	- - - - - - 0.7	2.0 0.4 -	V Ω pF	$I_{F} = \pm 10 \text{mA}, V_{CE} = 10 \text{V}$ $I_{F} = \pm 10 \text{mA}, I_{C} = 0.5 \text{mA}$ $V_{IO} = 500 \text{Vdc},$ $40 \sim 60\% \text{ R.H.}$ $V_{IO} = 0, f = 1 \text{MHz}$ $V_{CC} = 10 \text{V},$
Transfer ratio CTR Symm Collector-e saturation Isolation re Input-outpu Turn-on tim	H11AA2 H11AA3 H11AA4 hetry mitter voltage esistance ut capacitance he	V _{CE(sat)} R _{IO} C _{IO} T _{on}	10 50 100 0.5 - 10 ¹¹ - -	- - - - - - 0.7 -	2.0 0.4 - - 10	VΩ	$I_{F} = \pm 10 \text{mA}, V_{CE} = 10 \text{V}$ $I_{F} = \pm 10 \text{mA}, I_{C} = 0.5 \text{mA}$ $V_{IO} = 500 \text{Vdc},$ $40 \sim 60\% \text{ R.H.}$ $V_{IO} = 0, f = 1 \text{MHz}$
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* Typical values at $T_a = 25^{\circ}C$

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Typical Electro-Optical Characteristics Curves





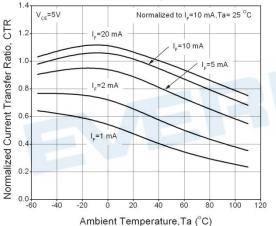
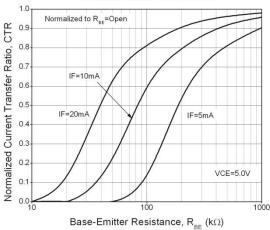


Figure 5. Current Transfer Ratio (Unsaturated)

vs Base-Emitter Resistance



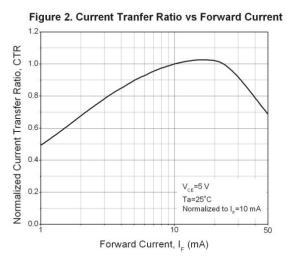
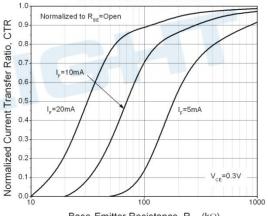
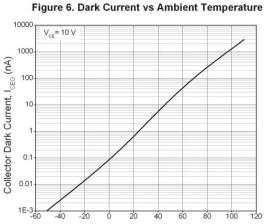


Figure 4. Current Transfer Ratio (Saturated) vs Base-Emitter Resistance







Ambient Temperature, Ta (°C)

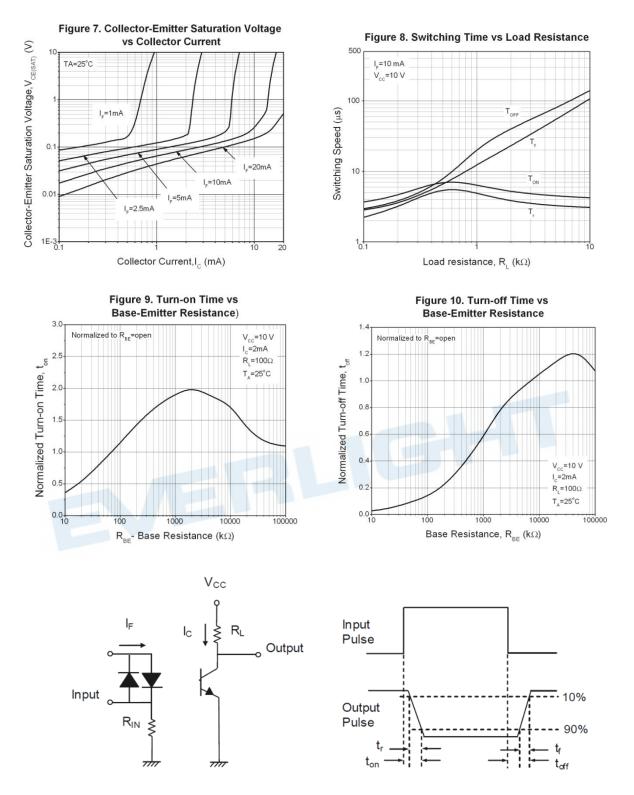


Figure 11. Switching Time Test Circuit & Waveforms

DATASHEET **6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER** AC INPUT PHOTOCOUPLER H11AAX Series

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Order Information

Part Number



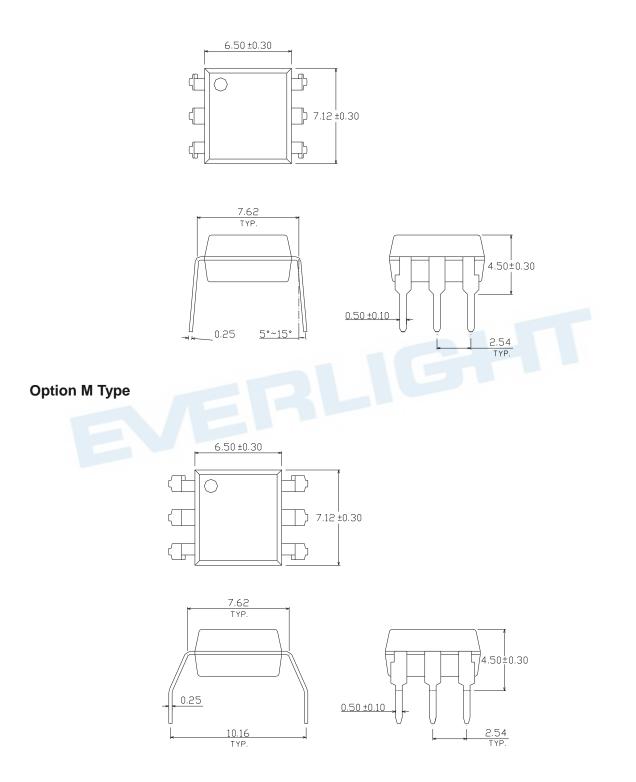
Notes

- Х = CTR Rank (1, 2, 3, or 4)
- Υ = Lead form option (S, S1, M or none)
- Ż = Tape and reel option (TA, TB, or none).
- = VDE safety (optional).

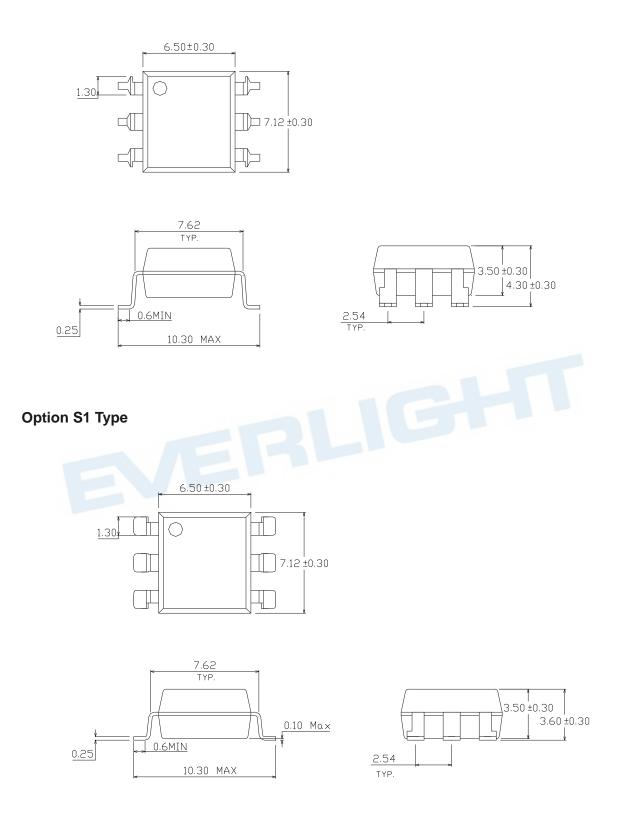
Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
М	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

Package Dimension (Dimensions in mm)

Standard DIP Type



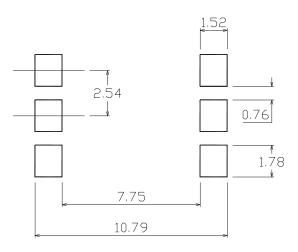
Option S Type



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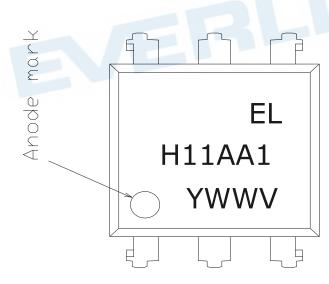
Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

Device Marking

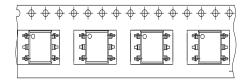


Notes

EL	denotes Everlight
H11AA1	denotes Part Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE safety (optional)

Tape & Reel Packing Specifications

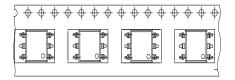
Option TA





Direction of feed from reel

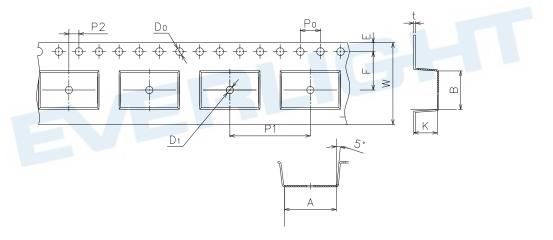
Option TB





Direction of feed from reel

Tape dimensions



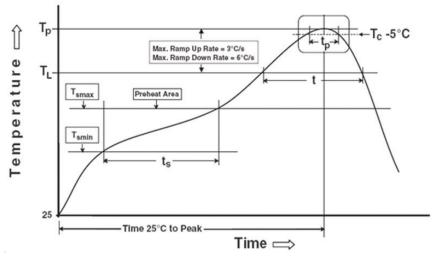
Dimension No.	Α	В	Do	D1	E	F
Dimension (mm)	10.8±0.1	7.5±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1
Dimension No.	Ро	P1	P2	t	w	к
Dimension (mm)	4.0±0.15	12±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1



Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Notes

Preheat			
Temperature min (T _{smin})	150 °C		
Temperature max (T _{smax})	200°C		
Time (T _{smin} to T _{smax}) (t _s)	60-120 seconds		
Average ramp-up rate (T _{smax} to T _p)	3 °C/second max		
Other			

Other

.

Liquidus Temperature (T_L) Time above Liquidus Temperature (t L) Peak Temperature (T_P) Time within 5 °C of Actual Peak Temperature: TP - 5°C Ramp- Down Rate from Peak Temperature Time 25°C to peak temperature Reflow times

217 °C 60-100 sec 260°C 30 s 6°C /second max. 8 minutes max. 3 times

Reference: IPC/JEDEC J-STD-020D

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